Synthesis, Crystal Structure, Chemical Bonding, and Physical Properties of the Ternary Na/Mg Stannide Na₂MgSn

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S Supporting Information

[AB](#page-5-0)STRACT: [A ternary sta](#page-5-0)nnide of sodium and magnesium, Na₂MgSn, was synthesized from the elements, and the crystal structure was determined by single-crystal X-ray diffraction. The compound crystallizes in the Li₂CuAs structure type (hexagonal, $P6_3/mmc$, $Z = 2$, $a = 5.0486(11)$ Å, $c = 10.095(2)$ Å), and its structure is built up of two-dimensional honeycomb layers of $\frac{2}{\infty}$ [(MgSn)^{2–}] stacked along the *c*-axis, with Na atoms as "space fillers". First-principles computations at various levels of density functional theory (DFT) verify that the most stable configuration is the one in which Na and Mg atoms occupy the 4f and 2b sites, respectively, and thus DFT provides a necessary complement to X-ray structural elucidation. Our computations also predict that Na₂MgSn must be a semiconductor with a small band gap. In accord with these predictions, the electrical resistivity measured for a polycrystalline sample of Na₂MgSn is 9.6–10.4 mΩ cm in the range of 90–635 K, and the Seebeck coefficient decreases from +390 μ V K⁻¹ (at 300 K) to +150 μ V K⁻¹ (at 430 K).

1. INTRODUCTION

Within the last two decades, a wide variety of alkali-metal stannides has been synthesized, and their crystal structures exhibit most diverse tin subunits and networks, ranging from zero to three in dimensionality.¹⁻¹² In the alkali—alkalineearth-Sn ternary systems, multiple structural fragments and networks are to be expected i[n](#page-5-0) [th](#page-6-0)e solid-state structures, because of differences in valence electron numbers and size between alkali and alkaline-earth metal cations. In the past decade, Sevov and co-workers have intensively explored such ternary phases and synthesized $\text{Li}_5\text{Ca}_7\text{Sn}_{11}^{13}$ $\text{Li}_{8.84}\text{CaSn}_{6.16}^{13}$ $\rm Li_4Ba_3Sn_8$,¹⁴ $\rm Na_8BaSn_6$,¹⁵ $\rm Na_{10}(Ca,Sr)Sn_{12}$,¹⁶ and $\rm Na_4CaSn_6$.¹⁷ Most compounds exhibit novel crystal [s](#page-6-0)tructures wi[th](#page-6-0) characteri[stic](#page-6-0) compon[ent](#page-6-0)s, for example, [aro](#page-6-0)matic pentago[ns](#page-6-0) of $\left[Sn_{5}\right]^{6-}$ (ref 13) or a large isolated cluster of $\left[Sn_{12}\right]^{12-}$ (ref 16). The ternary compounds are semiconductors with energy gaps of 0.11−4 [eV](#page-6-0), except for the highly conductive $Li_5Ba_7Sn_{11}$ [an](#page-6-0)d $\text{Li}_{9-x}\text{CaSn}_{6+x}$. Recently, Lei prepared two ternary compounds, K₂Mg_{5−x}Sn₃ and K₃Mg₁₈Sn₁₁ in the K–Mg–Sn system, and reported their crystal and electronic structures.¹⁸ $K_2Mg_{5-x}Sn_3$ and $K_3Mg_{18}Sn_{11}$ contain a two-dimensional (2-D) corrugated Mg−Sn network and a three-dimensional (3-[D\)](#page-6-0) $[Mg_{18}Sn_{11}]$ network, respectively, and it is anticipated that both compounds are metallic.

Despite these efforts, an abundance of phases in the alkali alkaline-earth-Sn system yet await their discovery, and such phases also promise a highly diverse structural chemistry. For example, there is no report so far on Na−Mg−Sn ternary compounds. In the present study, we report synthesis, crystal structure, and electronic as well as physical properties of Na₂MgSn, which is built up from 2-D honeycomb layers of $\frac{2}{\infty}$ [(MgSn)^{2–}] with Na atoms as "space fillers".

2. EXPERIMENTAL PROCEDURES AND COMPUTATIONAL DETAILS

Synthesis. All manipulations were carried out in an argon gas-filled glovebox (MBraun, O_2 , $H_2O < 1$ ppm), because of the air sensitivity of the reagents and samples. Sodium (lump, 99.95%, Nippon Soda Co., Ltd.), magnesium (powder, <104 μm, 99.9%, Rare Metallic Co., Ltd.), and tin (shot, 99.999%, Koujundo Kagaku Co., Ltd.) were weighed in predetermined molar ratios. A sintered BN crucible (inside diameter = 6 mm; depth = 18 mm in inner volume, Showa Denko, 99.5%) was loaded with the source elements (ca. 0.8 g in total) and sealed in a stainless steel tube (SUS316, an inner diameter of 10.5 mm, a length of 90 mm) with stainless steel caps. For the preparation of a polycrystalline bulk of Na₂MgSn, the stoichiometric amounts of the source elements were heated at 823 K for 24 h. The product was pulverized with an agate mortar and pressed into a compact (ca. 14 $mm \times 3 mm \times 2.5 mm$, which was then sintered at 913 K for 18 h in an electrical furnace. Single crystals of $Na₂MgSn$ were obtained by heating the source elements with a molar ratio of Na:Mg:Sn = 3:1:1 at 1023 K for 3 h, followed by cooling to 873 K at a rate of −5 K/h, and subsequent cooling to room temperature in the furnace by shutting off the electric power.

Structure Elucidation. The powder X-ray diffraction (XRD) pattern of Na₂MgSn was measured under an argon atmosphere using Cu Ka radiation (λ = 1.5418 Å) with a pyrolitic graphite monochromator, a scintillation counter, and a diffractometer (Rigaku, Model RINT2200). The XRD data of a Na₂MgSn single crystal sealed in a glass capillary were collected using Mo K α radiation with a graphite monochromator and an imaging plate on a single-crystal Xray diffractometer (Rigaku, Model R-AXIS RAPID-II). XRD data collection and unit-cell refinement were performed by the PROCESS-AUTO program.¹⁹ An analytical absorption correction was applied by the NUMABS program.²⁰ The crystal structure was refined by fullmatrix least-squ[are](#page-6-0)s on F^2 using the SHELXL-97 program.²¹ All calculations were carried [ou](#page-6-0)t on a personal computer using the WinGX

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software package. 22 The atomic coordinates were standardized by the STRUCTURE TIDY program.²³

Electrical Pr[ope](#page-6-0)rties. The electrical resistivity of the polycrystalline sample was measured in [ar](#page-6-0)gon by a direct current four-probe method in the temperature range of 90−645 K. The Seebeck coefficient was measured in argon by a thermoelectric power (ΔE) temperature difference (ΔT) method between 300 K and 430 K.

Quantum Chemistry. Electronic-structure computations were carried out using two different approaches: first, the all-electron scalarrelativistic Linear Muffin-Tin Orbital (LMTO) theory^{24,25} in its tightbinding representation,²⁶ using the TB-LMTO-ASA 4.7 program,²⁸ [a](#page-6-0)nd second, a plane-wave projector-augmented wave²⁹ approach, as implem[en](#page-6-0)ted in the Vienna Ab Initio Simulation pa[cka](#page-6-0)ge (VASP).³⁰ To treat electronic exchange and correlation, the for[mul](#page-6-0)ations by v[on](#page-6-0) Barth and Hedin³¹ and Perdew, Burke, and Ernzerhof (PBE)³² we[re](#page-6-0) used in LMTO and VASP, respectively. Experimental structures were taken as input a[nd](#page-6-0) Na and Mg permuted where appropriate t[o o](#page-6-0)btain different structural models; these are described in detail below. k-space was sampled at points on a 16 × 16 × 8 Monkhorst–Pack grid³³ centered at the Γ point. Chemical bonding in Na₂MgSn was investigated using the Crystal Orbital Hamilton Population (COH[P\)](#page-6-0) technique,³⁴ which is an energy-resolved partitioning of the band structure energy (sum of the Kohn−Sham eigenvalues), in terms of atomic an[d](#page-6-0) bonding contributions.³⁵ As such, "off-site" COHP plots for orbital−pair interactions serve as an indicator of chemical bonding bet[w](#page-6-0)een two atoms 36 and we draw them in the conventional way: −COHP(E) is plotted such that bonding contributions fall to the right of the energy axis, [and](#page-6-0) antibonding contributions to the left.

3. RESULTS AND DISCUSSION

3.1. Synthesis. Mass change was not detected after heating the elements in the BN crucible at 823 K for 24 h. The product in the crucible was powdered and pressed into a rectangular parallelepiped compact in the glovebox. A polycrystalline silvergray bulk (13.1 mm \times 2.9 mm \times 2.5 mm) was obtained by heating the compact at 913 K for 18 h. A mass loss of ∼1% was observed after heating, suggesting that a trace of Na and/or Mg evaporated during the heating. The density of the sample was $2.12~{\rm g~cm^{-3}}$, corresponding to ca. 75% of the theoretical density determined in a later section. The bulk sample was powdered for X-ray diffraction (XRD) measurement; the powder XRD pattern of the sample, measured under an argon atmosphere, is shown in Figure 1. All peaks, except a small one at $2\theta = 21.4^{\circ}$, were indexed in the hexagonal system with unit-cell parameters of $a = 5.056(5)$ Å, $c = 10.098(8)$ Å. The XRD pattern is similar to that of the ternary compound $\text{Na}_2\text{CdSn}^{37}$ which adopts the

Figure 1. Powder XRD pattern of the sample prepared at 913 K for 18 h.

Li₂CuAs-type structure (hexagonal, $a = 4.990 \text{ Å}$, $c = 10.111 \text{ Å}$). The small unidentified peak observed at 21.4° was attributed to an impurity phase that was assumedly formed due to the evaporation of Na and/or Mg during heating. Since the amount of the impurity phase is small, judging from the XRD pattern and from the aforementioned mass loss of only 1%, the hexagonal crystalline phase is regarded to have a stoichiometric composition, namely, $Na₂MgSn$, in the sequel.

Flaky single crystals, silver-gray in color, with 0.03−0.20 mm in size were selected from the crushed sample prepared by heating the source elements with a molar ratio of $Na:Mg:Sn =$ 3:1:1 at 1023 K for 3 h with subsequent slow cooling.

3.2. Crystal Structure. The single-crystal XRD reflections of Na₂MgSn were indexed with hexagonal unit-cell parameters of $a = 5.0486(11)$ Å and $c = 10.095(2)$ Å, which are in agreement with those of the polycrystalline sample. The observed extinction conditions were consistent with space group $P6_3/mmc$ (No. 194). The crystal structure of Na₂CdSn³⁷ was adopted as an initial model for structure refinement. Na rests on the Wyckoff position 4f $\binom{1}{3}$, $\binom{2}{3}$, $z = 0.58$) of spa[ce](#page-6-0) group $P6_3/mmc$. There are reports on mixed Mg/Sn sites in the structures of some stannides, $38-40$ and thus Mg/Sn mixed occupations were initially assumed for both the 2b $(0, 0, \frac{1}{4})$ and 2 c ($\frac{1}{3}$, $\frac{2}{3}$, $\frac{1}{4}$) sites. The [occup](#page-6-0)ancy factors on the 2b and 2c sites were refined to be $Mg/Sn = 1.0/0.0$ and $Mg/Sn = 0.0/$ 1.0, respectively. Thus, Mg fully occupies the 2b site in Na2MgSn while Sn must rest on 2c. Because the X-ray beam cannot distinguish Na $(Z = 11)$ from Mg $(Z = 12)$, the assignment of Na and Mg was later checked from electronicstructure computations (see below), and it proved to be correct. The final refinement resulted in $R1 = 0.031$ and $S =$ 1.16 for all data, and the refined z coordinate of the Na atom was 0.5797(4). Details of the data collection and refinement are listed in Table 1. Atomic coordinates and equivalent displacement parameters (U_{eq}) , as well as selected bond lengths and angles, are sum[m](#page-2-0)arized in Tables 2 and 3.

As shown in Figures 2 and 3, Mg (2b site) and Sn (2c site) atoms lie in the same plane and f[orm](#page-2-0) ho[ne](#page-2-0)ycomb lattice layers that stack in an ABAB [se](#page-2-0)que[nce](#page-2-0) with an interlayer distance of 5.0475(10) Å along the c-axis. The atomic distance between Mg and Sn, d(Mg−Sn), in the honeycomb layer is 2.9148(3) Å and, thus, is slightly smaller than that in Mg_2Sn , adopting the anti-CaF₂ structure type with $d(Mg-Sn) = 2.927 \text{ Å}^{41}$ Ternary compounds of CaMgSn and $SrMgSn⁴²$ reported by Eisenmann et al. contain folded honeycomb lattice layers of 2 _∞[[\(M](#page-6-0)gSn)^{2–}] within their crystal structures. The $d(Mg-Sn)$ $d(Mg-Sn)$ values in the layers of CaMgSn (2.930 and 2.931 Å) are close to the $d(Mg-$ Sn) values we observe in Na₂MgSn, whereas the *d*(Mg–Sn) of 2.963 and 3.056 Å in SrMgSn are larger than those in the newly made Na₂MgSn.

Na atoms are located above and below the center of the sixmembered rings of $[Mg-Sn]_3$, and the atomic arrangement of Na is similar to that of C in lonsdaleite (hexagonal diamond), as shown in Figure 2. The Naⁱ–Naⁱⁱ distance across the honeycomb layers is 3.329(3) Å, which is smaller than that of Naⁱⁱ—Naⁱⁱⁱ (3.438(6) [Å\)](#page-2-0) between adjacent honeycomb lattice layers. The Na−Na interatomic distances are 6%−9% smaller than those in elemental Na.⁴³

The z-coordinate of the Na atom is 0.5797(4), which slightly deviates from that (0.5816([4\)](#page-6-0)) in the isostructural compound $\text{Na}_2\text{CdSn.}^{37}$ The interatomic distances $d(\text{Na}^{\text{i}}-\text{Na}^{\text{ii}})$ and $d(Na^{ii}-Na^{iii})$ in $Na₂CdSn$ are 3.405(1) and 3.327(1) Å,

Table 1. Crystal Data and Refinement Results for Na₂MgSn

respectively; they are almost equal to the Na−Na distances found in $Na₂MgSn$.

As shown in Figure 3, $Naⁿ$ and $Sn¹$ atoms align along the caxis with an interatomic distance of 3.328(4) Å. The $\text{Na}^{\text{ii}}\text{-}\text{Sn}$ distance is 3.384(2) Å and equals the shortest $\text{Na}^{\text{ii}}\text{--}\text{Mg}$ distance. These Na−Sn distances are close to the shortest one in the binary compound NaSn $(d = 3.355 \text{ Å})$.⁴

According to the compilation in Pearson's structural database,⁴⁴ only three ternary compounds containing the elements Na and Mg were previously known (if one ignores hydrides and halides): $\text{Na}_{2.5}\text{Mg}_{2.5}\text{Ga}_{9}^{4.5}$ NaMgAs, and NaMgSb.⁴⁶ Of those compounds, $Na_{2.5}Mg_{2.5}Ga₉$ has six mixed sites occupied by Na and Mg in t[he](#page-6-0) crystal structure, while th[e t](#page-6-0)wo pnictides contain no mixed occupancies. The

Table 3. Selected Bond Lengths and Angles in Na₂MgSn

bond pair	bond length (A)	bond angle vertices	bond angle $(°)$
$Nai-Naii$	3.438(6)	$Nai-Naii-Naiii$	118.90(14)
$Naii-Naiii$	3.329(3)	$Naiii - Na - Naiii$	98.61(11)
$Na^{i}-Mg$	3.384(2)	$Nai-Naii-Sn$	59.47(6)
$Naii-Mg$	3.384(2)	$Nai-Naii-Sni$	180.00
$Na^{i}-Sn$	3.384(2)	$Sn-Na^{ii}-Sn^{i}$	120.53(7)
$Naii-Sn$	3.384(2)	$Mg-Na^{ii}-Sn^{i}$	120.53(7)
$Naii-Sni$	3.328(4)	$Mg-Na^i-Sn$	51.02(3)
$Mg-Sn$	2.9148(3)	$Mg-Na^i-Sn$	51.02(3)
		$Mg-Sn-Mg$	120.00
		$Sn-Mg-Sn$	120.00

Figure 2. Schematic drawing of the crystal structure of Na₂MgSn. Na atoms are drawn in teal, Mg in yellow, and Sn in gray.

Figure 3. Atom coordination around a Na atom. Atoms are drawn as 75% probability ellipsoids. Symmetry codes: (i) $-x$, $-y$, $-z$, (ii) $-x$, $-z$ $y, -z + \frac{1}{2}$, and (iii) $x, y, -z + \frac{1}{2}$.

pnictides are composed of bent 2D square lattice layers of $\sqrt{2}$ _∞[Mg(As,Sb)[−]] stacked with Na atoms. The shortest Na−Mg distances reported for the structures of NaMgAs and NaMgSb are 3.438 Å and 3.612 Å, respectively, which are 1.6% and 6.7% larger than that of Na₂MgSn $(d = 3.384(2)$ Å).

Summing it up, the refined solid-state structure of $Na₂MgSn—in particular, regarding the interactionic distan$ ces-is consistent with the crystal structures of isostructural and other structurally related compounds. However, it is impossible to distinguish Na from Mg, which are direct

Table 2. Atomic Coordinates and Anisotropic and Isotropic Displacement Parameters.^a

 $U_{11} = U_{22}$, $U_{23} = U_{13} = 0$, $U_{eq} = (\sum_i \sum_j U_{ij} a_i)$ a_j a_i $\cdot a_j$

neighbors in the periodic table of the elements, by XRD experiment alone, because of the similar atomic scattering factors. Indeed, a refinement of the structure based on a structural model with Na/Mg mixed sites (and a restriction of the chemical composition to $Na₂MgSn$, of course) resulted in Na site occupancies of 58% and 16% at 4f and 2b, respectively, with $R1 = 3.0\%$ and $S = 1.17$ for all data. The reliability factors were virtually equal to those of the ordered model $(R1 = 3.1\%)$ $S = 1.16$: in other words, no definitive assessment is possible from refinement alone. To circumvent this issue and unambiguously clarify the Na/Mg positions in the crystal, we performed a complementary, quantum-chemical investigation, which is reported in the next section.

3.3. Quantum-Chemical Computations. To verify the ordering configuration of Na and Mg in the crystal structure of Na2MgSn, we performed theoretical computations in the framework of density-functional theory (DFT), which has become the method of choice for most solid-state quantum chemical questions.³⁵ Our aim is 2-fold: we seek to (1) distinguish possible distributions of Na and Mg in the crystal by evaluating the cor[res](#page-6-0)ponding electronic energies, and (2) understand the electronic structure and chemical bonding in the newly synthesized compound. We chose two principally different routes, to avoid ambiguities in one particular DFT method: namely, we performed tight-binding computations with a local basis set $(TB-LMTO-ASA)$ program),²⁴ as well as plane-wave DFT computations (using the VASP package).³⁰ Local (LDA) and semilocal (GGA) approxima[tio](#page-6-0)ns to the exchange-correlation functional were chosen, respectively, ag[ain](#page-6-0) to verify that our results are not exclusive to one particular method.

Regarding the structures derived from XRD, there are several possibilities of assigning Na and Mg atoms, and they are sketched in Figure 4: model (a) is a fragment cut from the proposed Li₂CuAs structure type, with only Mg in the

Figure 4. Motifs in the structural models for DFT computations on Na₂MgSn. Relevant fragments from the Li₂CuAs type structure $((a))$ and two hypothetical structures $((b)$ and (c)).

honeycomb layers, and only Na between the layers; models (b) and (c) represent two models with only Na in the honeycomb layers, and the remaining Na and Mg distributed around the honeycomb layers. In these cases, the space group lowers to $P6_3/mc$ and P3m1, respectively. Quick single-point computations immediately verify that both models (b) and (c) with Na in the honeycomb layers may be safely discarded; the energetic cost is predicted to be 45.4–49.3 kJ mol⁻¹ (LDA) or 63.0−67.1 kJ mol⁻¹ (GGA), as given in Table 4; the slight differences caused by the two fundamentally different DFT

methods (local orbitals versus plane waves) are unimportant in the light of this clear energetic preference toward the $Li₂CuAs$ type $(model (a))$.⁴⁷ Finally, one may think of mixed occupations in the honeycomb layer (i.e., Na and Mg sharing what was assigned a[s t](#page-6-0)he 2b site). We thus set up "2 \times 2 \times 1" supercells (doubling the experimentally determined cell in the a and b directions) in which we randomly permuted various Na and Mg atoms, such that a certain amount of Na atoms occupied the former Mg positions in the honeycomb lattice; of course, the chemical composition of all supercells remained unchanged. The resulting VASP energies are plotted in Figure 5, and they show an almost linear increase in energy as more Na is placed into the honeycomb layers. These results safely

Figure 5. Dependence of the computed energies (DFT/GGA) for Na2MgSn on the occupancy of Na atoms on the proposed Mg positions ("2b site"). Filled diamonds (\triangleleft) correspond to the structural models shown in Figure 4 (marked as a, b, and c), while open diamonds (\diamondsuit) refer to supercell computations as described in the text. The dashed line serves only as a guide to the eye.

eliminate the possibility of Na/Mg mixed occupations in the structure. The propositions of the preceding section are thus proven correct quantum-chemically: $Na₂MgSn$ crystallizes in the $Li₂CuAs$ structure type.

To gain further insight into the chemical bonding, we computed the densities of states (DOS, given in states eV[−]¹ cell[−]¹) as well as the crystal orbital Hamilton populations (−COHP, per bond) for the respective nearest-neighbor interactions in $Na₂MgSn$, and these curves are shown in Figures 6 and 7, respectively. Integrated −COHP (−ICOHP) were computed and tabulated in Table 5. The (P)DOS plots indicate [tw](#page-4-0)o w[el](#page-4-0)l-separated sets of bands in the valence region, namely, an area of mainly s character [at](#page-4-0) −8 eV to −6.5 eV (relative to the Fermi level, ε_F), and a more p-dominated area starting at approximately −3.75 eV; this is not unexpected for

Figure 6. Total and partial densities-of-states (DOS, PDOS, respectively) of Na₂MgSn obtained from TB-LMTO-ASA computations. In the PDOS curves, the gray shaded area indicates the total DOS for comparison. A horizontal line marks the Fermi level $\varepsilon_{\rm F}$, which has been arbitrarily set to 0 eV throughout this work.

Figure 7. Selected crystal orbital Hamilton population (COHP) curves for atom-pair interactions in Na2MgSn. Integrated −COHP values (−ICOHP) up to the Fermi level, for one bond each, are given at the head of the graphs.

Table 5. ICOHP up to the Fermi Level, Given per Bond and per Unit Cell, for Selected Bonds

bond	d(A)	$-ICOHP$ (eV/ bond)	\times N per cell	$-ICOHP$ (eV/ cell)		
$Nai-Naii$	3.438	0.018	$\times 2$	0.036		
Na ⁱⁱ -Na ⁱⁱⁱ	3.329	0.089	\times 6	0.534		
$Na^{ii}-Sn^{a}$	3.384	0.264	\times 12	3.168		
$Naiii-Sn$	3.329	0.403	\times 4	1.612		
$Na^{ii} - Mg^{a}$	3.384	0.186	\times 12	2.232		
$Mg-Sn$	2.915	1.98	\times 6	11.88		
a Na ⁱ and Na ⁱⁱ are equivalent in this case.						

this compound of main-group metals (additional l-resolved PDOS plots are provided in the Supporting Information). Furthermore, the DOS plot shows a small band gap of ∼0.4 eV above the Fermi level (ε_{F}) . It must [be noted that](#page-5-0) "pure" DFT typically underestimates the size of the gap, 35 and the computational prediction rather serves as a qualitative measure; nonetheless, Na₂MgSn is clearly predicted to [be](#page-6-0) a semiconductor, and this prediction will be tested, experimentally, in the next section. Looking at the chemical bonding, the top of the valence bands is dominated by Mg−Sn bonding interactions: a $-COHP(E)$ integration up to the Fermi level gives 1.98 eV per bond or 11.88 eV per unit cell, which is, by far, the largest contribution *per bond* among those shown in Figure 7. The second largest contributions are made by Na− hexagon bonds (Na"−Sn, Naⁱⁱⁱ−Sn, and Na"−Mg, respectively), out of which the covalent Naiii−Sn interaction is predicted to be strongest (but still weaker by a factor of 5 than the Mg−Sn bond). The three types of Na−hexagon bonds contribute ICOHP values of 3.17, 1.61, and 2.23 eV per unit cell, respectively, which together constitute 36% of the ICOHPs listed in Table 5. Remarkably, the Na−Na COHP interactions shown in Figure 7 are almost nonexistent, compared to the other bonds (mind the different scales in the COHP plots); consequently, summing up over the entire unit cell, Na−Na pairs contribute a mere 3% of all ICOHP values listed in Table 5. Summarizing, Na₂MgSn can be regarded as a stacking of strongly bonded Mg−Sn honeycomb layers that are linked by less strong Na−Mg and Na−Sn interactions.

3.4. Physical Properties. The electrical resistivity (ρ) and Seebeck coefficient (S) of a polycrystalline sample of Na₂MgSn are shown in Figure 8. The ρ value is 9.6 m Ω cm at 90 K and slightly increases to a maximum of 10.4 m Ω cm at 360 K.

Figure 8. (a) Electrical resistivity (ρ) and (b) Seebeck coefficient (S) of the polycrystalline sample of Na₂MgSn. The inset in panel a shows the electrical conductivity of $Na₂MgSn$ as a function of reciprocal temperature.

Beyond that, it gradually decreases with increasing temperature. Although the relative density of the $\text{Na}_2\text{Mg}\text{Sn}$ sample (75%) in the present study may not be sufficient to discuss the behavior of the electrical resistivity in a quantitative way, the ρ values are 3 orders of magnitude higher than those of the constituting metals (4.8 $\mu\Omega$ cm for Na,⁴⁸ 4.4 $\mu\Omega$ cm for Mg,⁴⁹ and Sn (10 $(\mu\Omega \text{ cm})^{50}$ at room temperature. The inset in Figure 8a is an Arrhenius plot of the c[ond](#page-6-0)uctivity. The acti[vat](#page-6-0)ion energy obtaine[d f](#page-6-0)rom the linear fit in the temperature range of 570− 635 K gives a value of $0.17(1)$ eV. These results, in accord with the DOS shown in Figure 7 (see discussion above), suggest that $Na₂MgSn$ is not a typical metal but a narrow-gap semiconductor.

The Seebeck coefficien[t](#page-4-0) (S) of the polycrystalline sample is +390 μ V K⁻¹ at 300 K, and it monotonically decreases with increasing temperature, reaching +150 μ V K⁻¹ at 430 K. The positive values of S indicate that holes are the majority carriers in $Na₂MgSn$. The maximum thermoelectric power factor of Na₂MgSn calculated with the formula S^2/ρ amounts to 1.5 \times 10^{-3} W m⁻¹ K⁻² at 300 K, ~40% of that of Bi₂Te₃ which is one of the best thermoelectric materials known to date ($\rho = 1.0 \text{ m}\Omega$) cm, S = 200 μ V K⁻¹, power factor = 4 × 10⁻³ W m⁻¹ K⁻² at room temperature 51). Further work will focus on the preparation of highly dense bulk $Na₂MgSn$ samples showing lower electrical resi[stiv](#page-6-0)ity, as well as the characterization of its thermal conductivity.

4. CONCLUSIONS

The novel intermetallic compound disodium magnesium stannide $(Na₂MgSn)$ was synthesized by heating stoichiometric amounts of the elements. The crystal structure of Na_2MgSn (hexagonal, $P6_3/mmc$, $Z = 2$, $a = 5.0486(11)$ Å, $c = 10.095(2)$ Å) was determined by combining X-ray single-crystal structure analysis with first-principles DFT calculations. Once more, both approaches prove to be symbiotic and together they provide a well-founded description of the crystal chemistry.⁵² Unambiguously, they arrive at a structure based on the $Li₂CuAs$ type with the following positions of atoms: Na on $4f\binom{1}{3}$, $\binom{2}{3}$, z) with $z = 0.5816(4)$; Mg on 2b (0, 0, $\frac{1}{4}$) and Sn on 2c $(\frac{1}{3}, \frac{2}{3}, \frac{1}{4})$. Computed DOS and−ICOHP values suggest that the covalent Mg−Sn bonds in the 2-dimensional honeycomb-lattice layer are strongest in the structure, and the electronic properties are mainly determined by the honeycomb layers, justifying our initial dubbing of the Na atoms as "space fillers". The electrical resistivity of the polycrystalline sample of $Na₂MgSn$ exhibits little temperature dependence in the range of 90−635 K, and the values of 9.6−10.4 m Ω cm are a few magnitudes larger than those of typical metals. The material's maximum Seebeck coefficient (S) is +390 μ V K⁻¹, and the thermoelectric power factor amounts to 1.5×10^{-3} W m⁻¹ K⁻² at 300 K.

■ ASSOCIATED CONTENT

6 Supporting Information

X-ray crystallographic data in CIF format and l-resolved partial densities of states (PDOS) plots from TB−LMTO−ASA computations. This material is available free of charge via the Internet at http://pubs.acs.org.

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